

Recent Results of the 3D-Stripixel Si Detectors

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Summary

Recent Results of the 3D-Stripixel Si Detectors

Zheng Li¹, D. Bassignana², Wei Chen¹, Shuhuan liu^{1,3}, David Lynn¹, G. Pellegrini²

¹ Brookhaven National Laboratory, Upton, NY 11973, USA

² Centro Nacional de Microelectrónica (IMB-CNM-CSIC), Campus Univ. Autónoma de Barcelona, 08193 Bellaterra, Barcelona (Spain)

³ Permanent address: Xian Jiaotong University, Xian, China

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Author: Dr LI, Zheng (BNL)

Co-authors: Dr BASSIGNANA, Daniela (CNM); Dr LYNN, David (BNL); Dr PELLEGRINI, Giulio (CNM); Dr LIU, Shuhuan (BNL); Ms CHEN, Wei (BNL)

Presenter: Dr LI, Zheng (BNL)

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